

MITSUBISHI LASER DIODES  
ML9XX15 SERIES

InGaAsP DFB-LD with EA modulator

TYPE  
NAME

**ML9XX15**

**DESCRIPTION**

ML9XX15 series are DFB (Distributed Feedback) laser diodes with a monolithically integrated EA (Electro-Absorption) modulator emitting light beam around 1550nm.

They are well suited for light source in longdistance digital transmission systems.

**FEATURES**

- 1550nm DFB laser diode
- Integrated EA modulator
- High-speed response (2.5Gb/s)
- High-side mode suppression ratio (typical 40dB)
- Low driving voltage (typical 2Vpp@Ex=12dB)

**APPLICATION**

Long - distance (~300km) / High bit-rate (2.5Gb/s) digital transmission system

**ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Conditions	Ratings	Unit
I <sub>F</sub>	Laser forward current (LD)	CW	200	mA
V <sub>RL</sub>	Laser forward voltage (LD)	—	2	V
V <sub>EA</sub>	Modulator voltage	—	0~−3	V
T <sub>c</sub>	Case temperature	—	+20~+30	°C
T <sub>stg</sub>	Storage temperature	—	−40~+100	°C

**ELECTRICAL/OPTICAL CHARACTERISTICS (T<sub>c</sub> = 25°C)**

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
I <sub>th</sub>	Threshold current	CW,V <sub>mod</sub> = 0V	—	20	30	mA
I <sub>OP</sub>	Operating current	CW,Po = 3mW,V <sub>mod</sub> = 0V	—	90	150	mA
V <sub>OP</sub>	Operating voltage	CW,Po = 3mW,V <sub>mod</sub> = 0V	—	1.5	2.0	V
η	Slope efficiency	CW,Po = 3mW,V <sub>mod</sub> = 0V	—	0.04	—	mW/mA
λ <sub>P</sub>	Peak wavelength	CW,Po = 3mW,V <sub>mod</sub> = 0V	1530	1550	1570	nm
θ <sub>  </sub>	Beam divergence angle (parallel)	CW,Po = 3mW,V <sub>mod</sub> = 0V	—	30	—	deg.
θ <sub>⊥</sub>	Beam divergence angle (perpendicular)	CW,Po = 3mW,V <sub>mod</sub> = 0V	—	35	—	deg.
P <sub>m</sub>	Monitoring output	CW,Po = 3mW,V <sub>mod</sub> = 0V	—	1.0	—	mW
f <sub>c</sub>	Cutoff frequency	CW,Po = 3mW,V <sub>mod</sub> = −1V	4.0	6.0	—	GHz
Ex	Extinction ratio	CW,Po = 3mW,V <sub>mod</sub> = −2.0V	10	12	—	dB
t <sub>r</sub> ,t <sub>f</sub>	Rise and fall time	2.48832Gb/s,NRZ,PRBS2 <sup>23</sup> −1	—	—	125	psec
SMSR	Side mode suppression ratio	mark ratio = 50%	30	40	—	dB
△λ <sub>-20</sub>	Spectrum width (20dB down)	If = I <sub>OP</sub> ,V <sub>PP</sub> = 2.0V	—	—	0.25	nm
P <sub>P</sub>	Power penalty	ditto 1.3 μmZDF350km @BER = 10 <sup>−10</sup>	—	0.0	—	dB

### TYPICAL CHARACTERISTICS

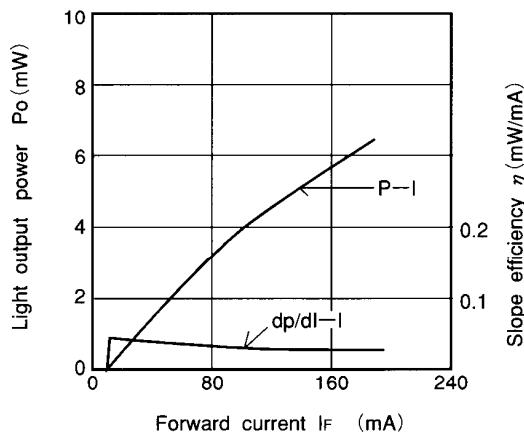


Fig.1 Light output vs. forward current

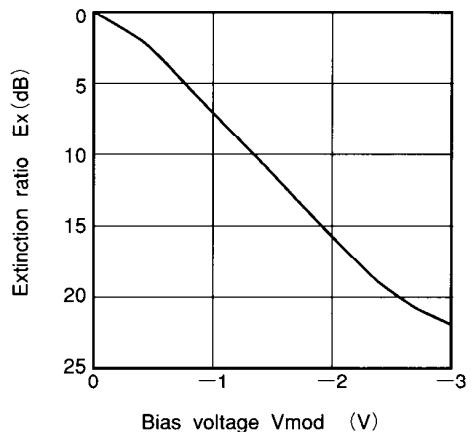


Fig.2 Extinction characteristics (DC)

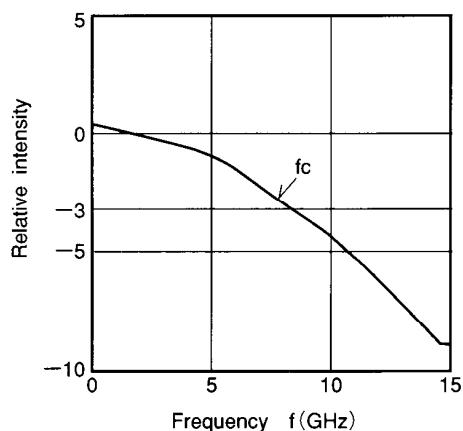


Fig.3 Frequency characteristics

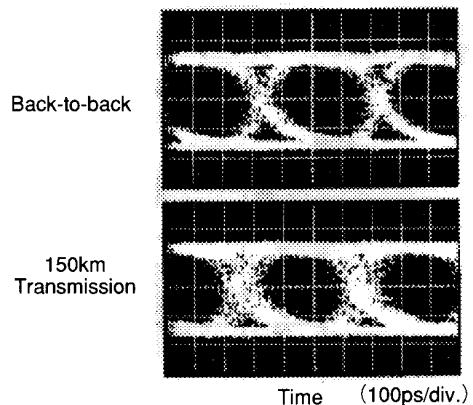


Fig.4 Waveform

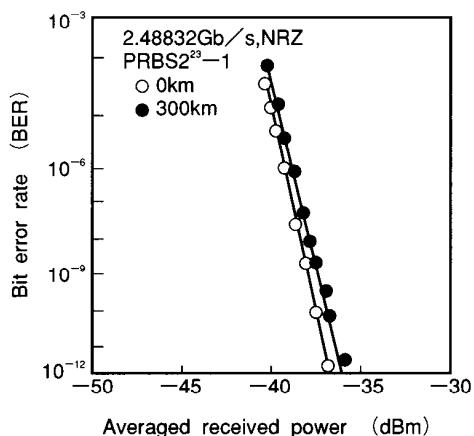


Fig.5 BER characteristics